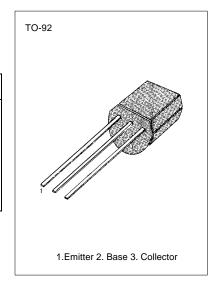
HIGH VOLTAGE TRANSISTOR

ABSOLUTE MAXIMUM RATINGS (T_A=25°C)

Characteristic	Symbol	Rating	Unit
Collector-Base Voltage	V _{CBO}	-350	V
Collector-Emitter Voltage	V_{CEO}	-350	V
Emitter-Base Voltage	V_{EBO}	-5	V
Collector Current	I _C	-500	mA
Base Current	I _B	-250	mA
Collector Dissipation	Pc	0.625	W
Derate above 25		5	mW/°C
Junction Temperature	TJ	50	°C
Storage Temperature	T _{STG}	-55 ~ 150	°C

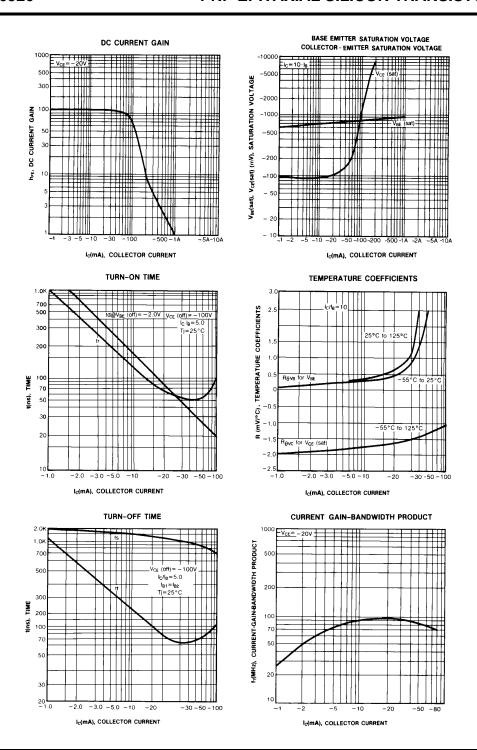


ELECTRICAL CHARACTERISTICS (T_A=25°C)

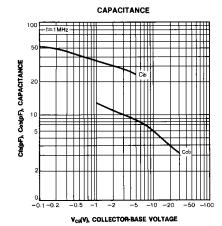
Characteristic	Symbol	Test Conditions	Min	Max	Unit
Collector-Base Breakdown Voltage * Collector-Emitter Breakdown Voltage Emitter-Base Breakdown Voltage Collector Cut-off Current Emitter Cut-off Current * DC Current Gain	BV _{CBO} BV _{CEO} BV _{EBO} I _{CBO} I _{EBO} h _{FE}	c= -100μA, c=0 c= -1mA, c=0 c= -1mA, c=0 c= -250V, c=0 c= -4V, c=0 c= -10V, c= -10V, c= -10MA c= -10V, c= -30mA c= -30mA	-350 -350 -5 -5 20 30 30	-50 -50	V V V nA nA
Collector-Emitter Saturation Voltage Base-Emitter Saturation Voltage	V _{CE} (sat) V _{BE} (sat)	V _{CE} = -10V, I _C = -50mA V _{CE} = -10V, I _C = -100mA I _C = -10mA, I _B = -1mA I _C = -20mA, I _B = -2mA I _C = -30mA, I _B = -3mA I _C = -50mA, I _B = -5mA I _C = -10mA, I _B = -1mA I _C = -20mA, I _B = -2mA	20 15	-0.30 -0.35 -0.50 -1 -0.75	>>>>>
Base-Emitter On Voltage * Current Gain Bandwidth Product Collector-Base Capacitance Emitter-Base Capacitance	V_{BE} (on) f_{T} C_{CB}	l _C = -30mA, l _B = -3mA V _{CE} = -10V, l _C = -100mA V _{CE} = -20V, l _C = -10mA V _{CB} = -20V, l _E =0, f=1MHz V _{EB} = -0.5V, l _C =0, f=1MHz	40	-0.85 -0.90 -2 200 6 100	V V V MHz pF pF
Turn On Time Turn Off Time	T _{ON}	$V_{BE} \ (off) = \ \ -2V, \ \ V_{CC} = \ \ -100V \\ I_C = \ \ \ \ -50mA, \ I_B 1 = \ \ \ \ -10mA \\ V_{CC} = \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ $		200 3.5	ns ns

^{*} Pulse Test: Pulse Width≤300µs, Duty Cycle≤2%











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